Dual Switching Diode Common Cathode

Features

• These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Rating	Symbol	Max	Unit
Reverse Voltage	V _R	70	V
Forward Current	١ _F	200	mA
Peak Forward Surge Current	I _{FM(surge)}	500	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR- 5 Board (Note 1) T _A = 25°C	P _D	200	mW
Derate above 25°C		1.6	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta J A}$	625	°C/W
Total Device Dissipation Alumina Substrate (Note 2) $T_A = 25^{\circ}C$	P _D	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	- 55 to +150	°C

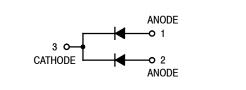
1. FR-5 = 1.0 \times 0.75 \times 0.062 in.

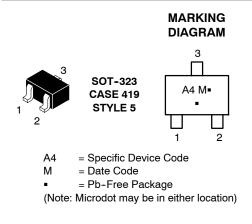
2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.



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ORDERING INFORMATION

Device	Package	Shipping [†]
BAV70WT1G	SOT-323 (Pb-Free)	3000 / Tape & Reel

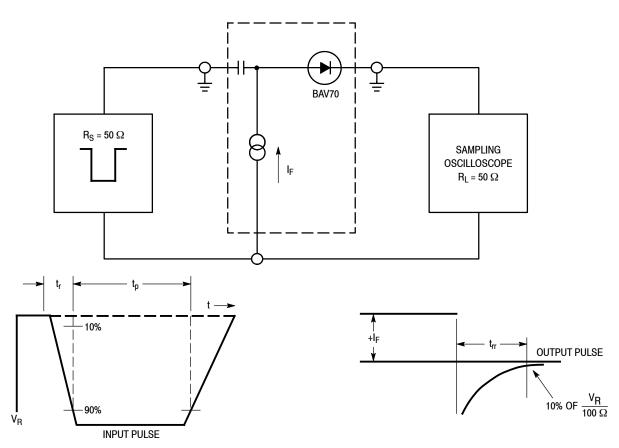
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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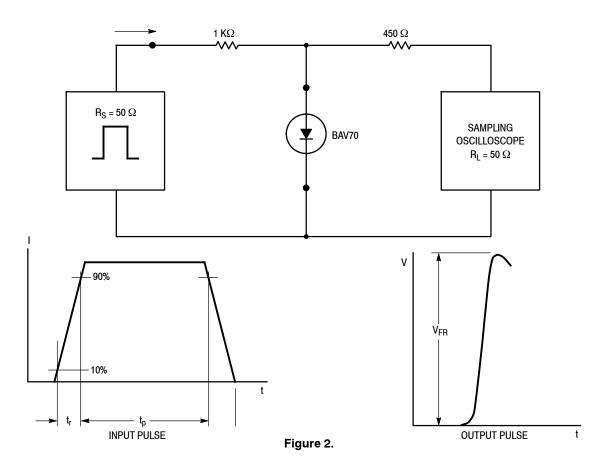
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Reverse Breakdown Voltage (I _(BR) = 100 μA)	V _(BR)	70	-	V
Reverse Voltage Leakage Current (Note 3) (V _R = 70 V) (V _R = 50 V)	I _R	-	5.0 100	μA nA
Forward Voltage $(I_F = 1.0 \text{ mA})$ $(I_F = 10 \text{ mA})$ $(I_F = 50 \text{ mA})$ $(I_F = 150 \text{ mA})$	V _F	- - -	715 855 1000 1250	mV
Diode Capacitance (V _R = 0 V, f = 1.0 MHz)	CD	-	1.5	pF
Reverse Recovery Time (I_F = I_R = 10 mA, R_L = 100 Ω , I_R(REC) = 1.0 mA) (Figure 1)	t _{rr}	-	6.0	ns
Forward Recovery Voltage $(I_F = 10 \text{ mA}, t_r = 20 \text{ ns})$ (Figure 2)	V _{RF}	-	1.75	V

3. For each individual diode while the second diode is unbiased.







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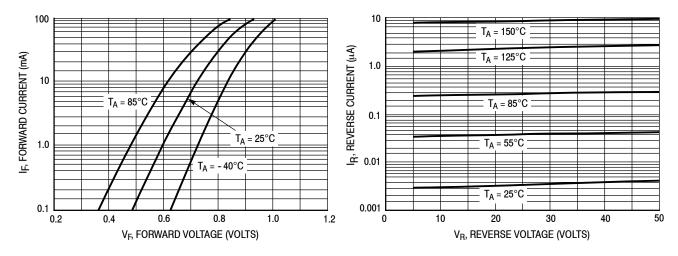




Figure 4. Leakage Current

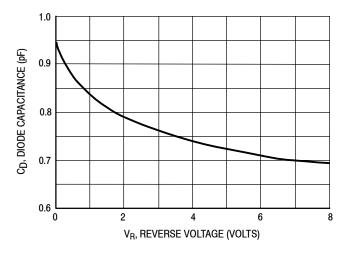
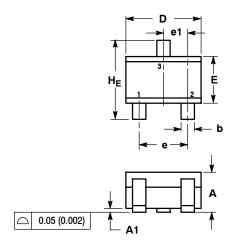
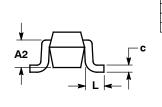


Figure 5. Capacitance

PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 ISSUE N



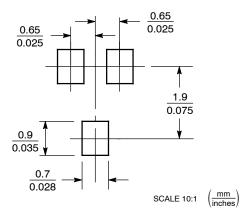


NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.80	0.90	1.00	0.032	0.035	0.040	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
A2	0.70 REF			0.028 REF			
b	0.30	0.35	0.40	0.012	0.014	0.016	
с	0.10	0.18	0.25	0.004	0.007	0.010	
D	1.80	2.10	2.20	0.071	0.083	0.087	
E	1.15	1.24	1.35	0.045	0.049	0.053	
е	1.20	1.30	1.40	0.047	0.051	0.055	
e1	0.65 BSC			0.026 BSC			
L	0.20	0.38	0.56	0.008	0.015	0.022	
HE	2.00	2.10	2.40	0.079	0.083	0.095	
STYLE	5:						



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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